NSN 5961-01-505-9364

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-505-9364 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** Between 0.9 millimeters and 1.1 millimeters **Overall Width:** Between 2.1 millimeters and 2.5 millimeters **End Application:** 4920-01-495-9100 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 reverse voltage, peak **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current absolute **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-emitter peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Product Name:** Diode, scd **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0